

MOSFETs Silicon P-Channel MOS (U-MOSVI)

TPCA8120

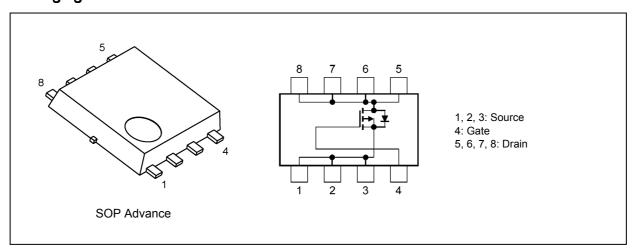
1. Applications

- · Lithium-Ion Secondary Batteries
- · Power Management Switches

2. Features

- (1) Small footprint due to a small and thin package
- (2) Low drain-source on-resistance: $R_{DS(ON)} = 2.4 \text{ m}\Omega$ (typ.) ($V_{GS} = -10 \text{ V}$)
- (3) Low leakage current: $I_{DSS} = -10 \mu A \text{ (max) (V}_{DS} = -30 \text{ V)}$
- (4) Enhancement mode: V_{th} = -0.8 to -2.0 V (V_{DS} = -10 V, I_D = -1 mA)

3. Packaging and Internal Circuit



4. Absolute Maximum Ratings (Note) (Ta = 25 °C unless otherwise specified)

Characteris	tics		Symbol	Rating	Unit
Drain-source voltage			V _{DSS}	-30	V
Gate-source voltage			V _{GSS}	-25/+20	1
Drain current (DC)		(Note 1)	I _D	-45	Α
Drain current (pulsed)		(Note 1)	I _{DP}	-135	1
Power dissipation	(T _c = 25 °C)		P _D	45	W
Power dissipation	(t = 10 s)	(Note 2)	P _D	2.8	W
Power dissipation	(t = 10 s)	(Note 3)	P _D	1.6	W
Single-pulse avalanche energy		(Note 4)	E _{AS}	263	mJ
Avalanche current			I _{AR}	-45	Α
Channel temperature			T _{ch}	150	°C
Storage temperature			T _{stg}	-55 to 150	1

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Start of commercial production



5. Thermal Characteristics

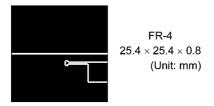
Characteristics			Symbol	Max	Unit
Channel-to-case thermal resistance	(T _c = 25 °C)		R _{th(ch-c)}	2.78	°C/W
Channel-to-ambient thermal resistance	(t = 10 s)	(Note 2)	R _{th(ch-a)}	44.6	°C/W
Channel-to-ambient thermal resistance	(t = 10 s)	(Note 3)	R _{th(ch-a)}	78.1	°C/W

Note 1: Ensure that the channel temperature does not exceed 150 °C.

Note 2: Device mounted on a glass-epoxy board (a), Figure 5.1

Note 3: Device mounted on a glass-epoxy board (b), Figure 5.2

Note 4: V_{DD} = -24 V, T_{ch} = 25 °C (initial), L = 0.1 mH, R_G = 25 Ω , I_{AR} = -45 A



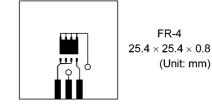


Fig. 5.1 Device Mounted on a Glass-Epoxy Board (a)

Fig. 5.2 Device Mounted on a Glass-Epoxy Board (b)

Note: This transistor is sensitive to electrostatic discharge and should be handled with care.



6. Electrical Characteristics

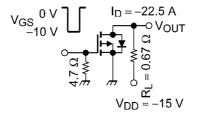
6.1. Static Characteristics ($T_a = 25$ °C unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage current	I _{GSS}	$V_{GS} = \pm 20 \text{ V}, V_{DS} = 0 \text{ V}$	_	_	±0.1	μΑ
Drain cut-off current	I _{DSS}	$V_{DS} = -30 \text{ V}, V_{GS} = 0 \text{ V}$			-10	
Drain-source breakdown voltage	V _{(BR)DSS}	$I_D = -10 \text{ mA}, V_{GS} = 0 \text{ V}$	-30			V
Drain-source breakdown voltage (Note 5)	V _{(BR)DSX}	I _D = -10 mA, V _{GS} = 10 V	-21	_		
Gate threshold voltage	V_{th}	$V_{DS} = -10 \text{ V}, I_{D} = -1 \text{ mA}$	-0.8	_	-2.0	
Drain-source on-resistance	R _{DS(ON)}	V _{GS} = -4.5 V, I _D = -22.5 A	_	3.1	4.0	mΩ
		V_{GS} = -10 V, I_D = -22.5 A		2.4	3.0	

Note 5: If a forward bias is applied between gate and source, this device enters $V_{(BR)DSX}$ mode. Note that the drain-source breakdown voltage is lowered in this mode.

6.2. Dynamic Characteristics (T_a = 25 °C unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Input capacitance	C _{iss}	V _{DS} = -10 V, V _{GS} = 0 V, f = 1 MHz	_	7420	_	pF
Reverse transfer capacitance	C _{rss}		_	1180	_	
Output capacitance	C _{oss}		_	1440	_	
Switching time (rise time)	t _r	See Fig. 6.2.1.	_	10	_	ns
Switching time (turn-on time)	t _{on}		_	18	_	
Switching time (fall time)	t _f		_	262	_	
Switching time (turn-off time)	t _{off}		_	762	_	



Duty \leq 1%, t_W = 10 μs

Fig. 6.2.1 Switching Time Test Circuit

6.3. Gate Charge Characteristics (T_a = 25 °C unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Total gate charge (gate-source plus gate-drain)	Qg	$V_{DD} \approx -24 \text{ V}, V_{GS} = -10 \text{ V}, I_{D} = -45 \text{ A}$	_	190		nC
Gate-source charge 1	Q _{gs1}		_	23		
Gate-drain charge	Q_{gd}		_	47		

6.4. Source-Drain Characteristics (T_a = 25 °C unless otherwise specified)

Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
Reverse drain current (pulsed)	(Note 6)	I _{DRP}	_	_	_	-135	Α
Diode forward voltage		V _{DSF}	I _{DR} = -45 A, V _{GS} = 0 V	_	_	1.2	V

Note 6: Ensure that the channel temperature does not exceed 150 °C.



7. Marking

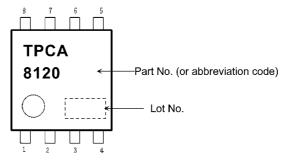


Fig. 7.1 Marking

8. Characteristics Curves (Note)

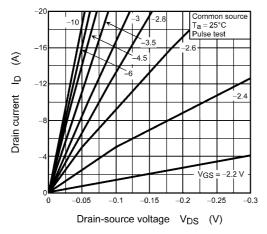


Fig. 8.1 I_D - V_{DS}

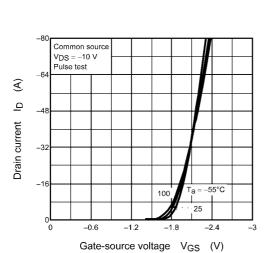


Fig. 8.3 I_D - V_{GS}

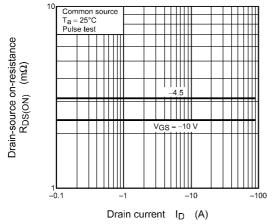


Fig. 8.5 R_{DS(ON)} - I_D

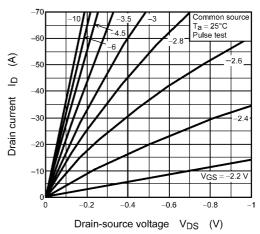


Fig. 8.2 I_D - V_{DS}

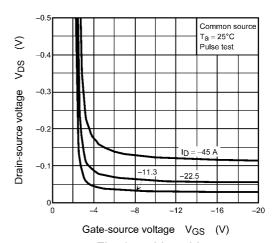


Fig. 8.4 V_{DS} - V_{GS}

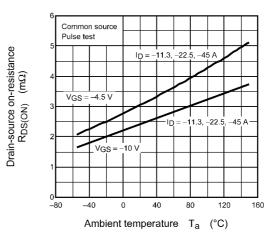


Fig. 8.6 R_{DS(ON)} - T_a

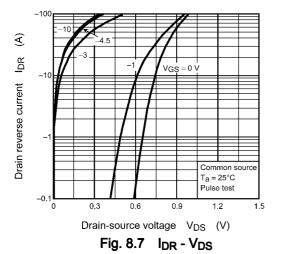


Fig. 8.8 Capacitance - V_{DS}

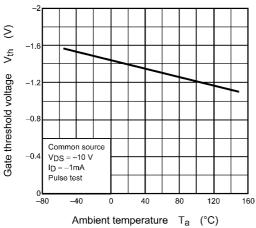


Fig. 8.9 V_{th} - T_a

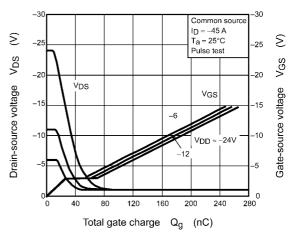


Fig. 8.10 Dynamic Input/Output Characteristics

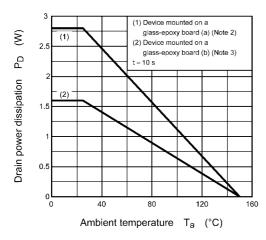


Fig. 8.11 P_D - T_a (Guaranteed Maximum)

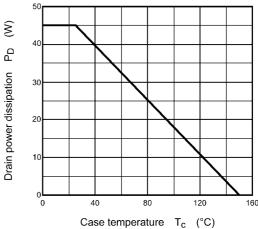


Fig. 8.12 P_D - T_c (Guaranteed Maximum)

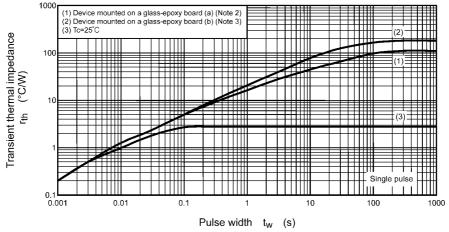


Fig. 8.13 r_{th} - t_w (Guaranteed Maximum)

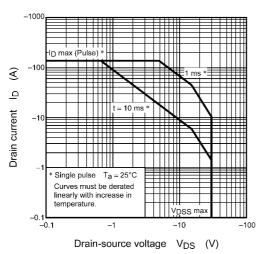


Fig. 8.14 Safe Operating Area (Guaranteed Maximum)

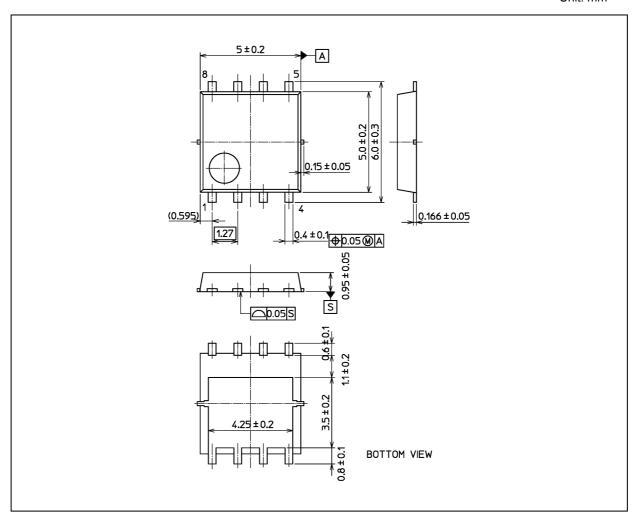
Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.

Rev.2.0



Package Dimensions

Unit: mm



Weight: 0.069 g (typ.)

	Package Name(s)
TOSHIBA: 2-5Q1S	
Nickname: SOP Advance	



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